## 2SD2139

## Silicon NPN triple diffusion planar type

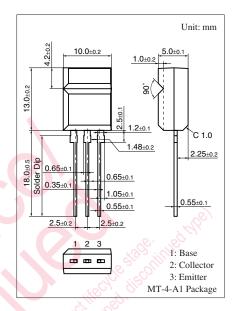
For high-speed switching and high current amplification ratio

### ■ Features

- High forward current transfer ratio h<sub>FE</sub>
- $\bullet$  Satisfactory linearity of forward current transfer ratio  $h_{\text{FE}}$
- Allowing supply with the radial taping

## ■ Absolute Maximum Ratings $T_C = 25$ °C

Parameter		Symbol	Rating	Unit	
Collector-base voltage (Emitt	$V_{CBO}$	80	V		
Collector-emitter voltage (Ba	V <sub>CEO</sub>	60	V		
Emitter-base voltage (Collector open)		V <sub>EBO</sub>	6	V	
Collector current		$I_C$	3	A	
Peak collector current		$I_{CP}$	6	A	
Base current		$I_B$	1	A	
Collector power dissipation		P <sub>C</sub>	15	W	
Ta	$_{\rm a} = 25^{\circ}{\rm C}$		2.0		
Junction temperature		T <sub>j</sub>	150	°C	
Storage temperature		$T_{stg}$	-55 to +150	°C	



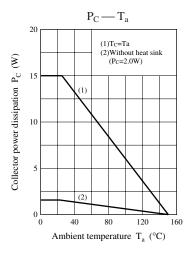
### ■ Electrical Characteristics $T_C = 25^{\circ}C \pm 3^{\circ}C$

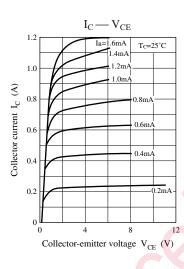
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	$I_{\rm C} = 25 \text{ mA}, I_{\rm B} = 0$	60			V
Collector-base cutoff current (Emitter open)	$I_{CBO}$	$V_{CB} = 80 \text{ V}, I_{E} = 0$			100	μΑ
Collector-emitter cutoff current (Base open)	$I_{CEO}$	$V_{CE} = 40 \text{ V}, I_{B} = 0$			100	μΑ
Emitter-base cutoff current (Collector open)	I <sub>EBO</sub>	$V_{EB} = 6 \text{ V}, I_{C} = 0$			100	μΑ
Forward current transfer ratio *	h <sub>FE</sub>	$V_{CE} = 4 \text{ V}, I_{C} = 0.5 \text{ A}$	500		2 500	_
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_C = 2 \text{ A}, I_B = 0.05 \text{ A}$			1.0	V
Transition frequency	$\mathbf{f}_{\mathrm{T}}$	$V_{CE} = 12 \text{ V}, I_{C} = 0.2 \text{ A}, f = 10 \text{ MHz}$		50		MHz

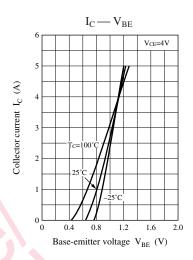
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

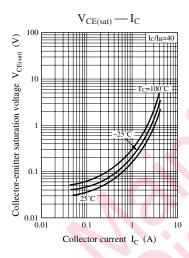
#### 2. \*: Rank classification

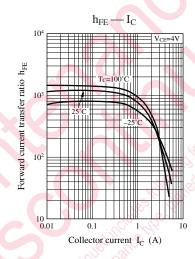
Rank	Q	Р	0
$h_{\mathrm{FE}}$	500 to 1 000	800 to 1 500	1 200 to 2 500

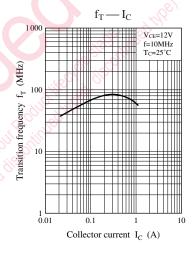


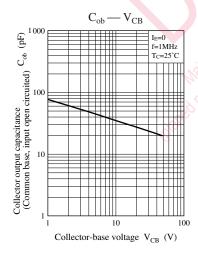


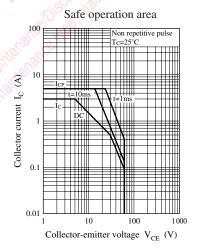


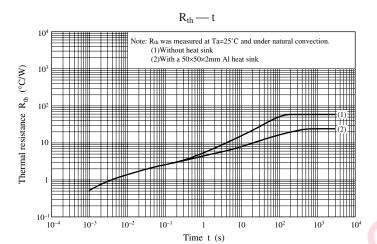












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